

BC817KH series

45 V, 500 mA NPN general-purpose transistors

Rev. 2 — 30 September 2025

Product data sheet

1. General description

NPN general-purpose transistors in a small SOT23 Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	PNP complement:	
	Nexperia	JEDEC	
BC817K-16H	SOT23	TO-236AB	BC807-16H
BC817K-25H			BC807-25H
BC817K-40H			BC807-40H

2. Features and benefits

- Three current gain selections
- High power dissipation capability
- High-temperature applications up to 175 °C

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current	T _{amb} = 25 °C		-	-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	1	А
h _{FE}	DC current gain						
	BC817K-16H	V_{CE} = 1 V; I_{C} = 100 mA ; T_{amb} = 25 °C	[1]	100	-	250	
	BC817K-25H		[1]	160	-	400	
	BC817K-40H		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base]3	С
2	Е	emitter		
3	С	collector		B—,
				E sym123
			SOT23	,

6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
BC817K-16H	SOT23	plastic, surface-mounted package; 3 leads	SOT23
BC817K-25H			
BC817K-40H			

7. Marking

Table 5. Marking

lable of marking		
Type number		Marking code [1]
BC817K-16H	[1]	%HD
BC817K-25H	[1]	%HE
BC817K-40H	[1]	%HF

[1] % = placeholder for manufacturing site code

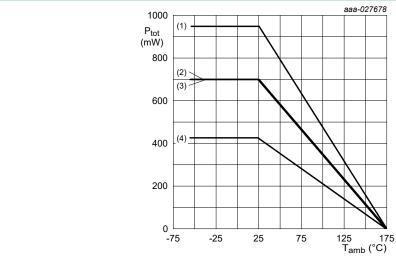
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	45	V
V_{EBO}	emitter-base voltage	open collector	open collector -		7	V
Ic	collector current			-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	1	А
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	425	mW
			[2]	-	700	mW
			[3]	-	700	mW
			[4]	-	950	mW
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB; 4-layer copper; tin plated and standard footprint.
- [4] Device mounted on an FR4 PCB; 4-layer copper; tin-plated; mounting pad for collector 1 cm².



- (1) FR4 PCB; 4-layer copper, 1 cm²
- (2) FR4 PCB; single-sided copper, 1 cm²
- (3) FR4 PCB; 4-layer copper; standard footprint
- (4) FR4 PCB; single-sided copper; standard footprint

Fig. 1. Power derating curves

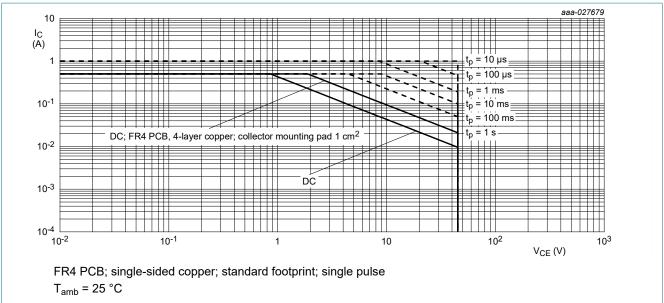


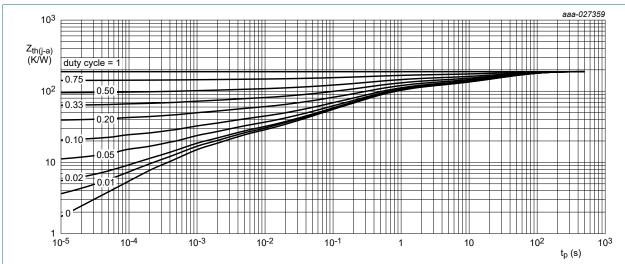
Fig. 2. Safe operating area; junction to ambient; continous and peak collector currents as a funtion of collectoremitter voltage

9. Thermal characteristics

Table 7. Thermal characteristics

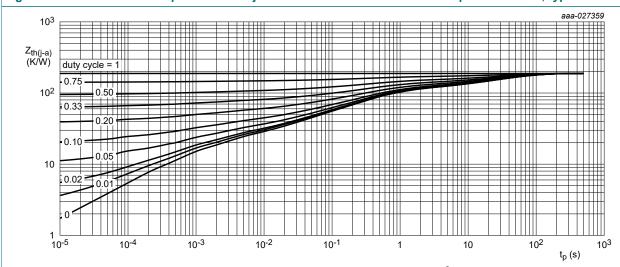
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air;	[1]	-	-	353	K/W
		T _{amb} = 25 °C	[2]	-	-	215	K/W
			[3]	-	-	215	K/W
			[4]	-	-	158	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	60	K/W

- [1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB; 4-layer copper; tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB; 4-layer copper; tin-plated; mounting pad for collector 1 cm².



FR4 PCB; single-sided copper; tin-plated and standard footprint

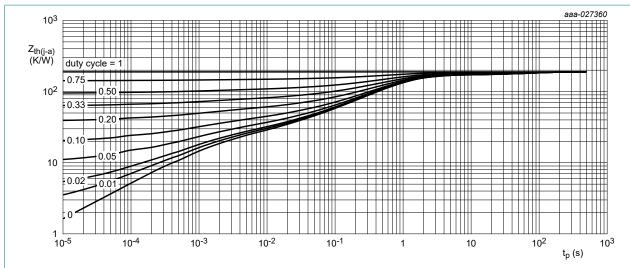
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm²

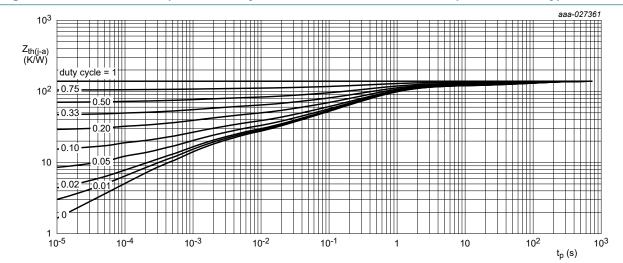
Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

Product data sheet



FR4 PCB; 4-layer copper; tin-plated and standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; 4-layer copper; tin-plated; mounting pad for collector 1 cm²

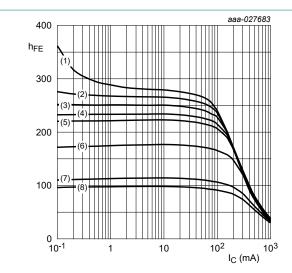
Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-		V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _B = 0 A; T _{amb} = 25 °C		45	-		V
V _{(BR)EBO}	emitter-base breakdown voltage	$I_E = 100 \ \mu A; I_C = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		7	-		V
I _{CBO}	collector-base	V _{CB} = 25 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	cut-off current	V _{CB} = 25 V; I _E = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain						
	BC817K-16H	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	100	-	250	
	BC817K-25H		[1]	160	-	400	
	BC817K-40H		[1]	250	-	600	
	BC817K-16H BC817K-25H BC817K-40H	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	700	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	1.2	V
V_{BE}	base-emitter voltage	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	-	-	1.2	V
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$		100	-	-	MHz
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	3	-	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz};$					
	BC817K-16H	T _{amb} = 25 °C		-	44	-	pF
	BC817K-25H			-	39	-	pF
	BC817K-40H			-	39	-	pF

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



 $V_{CE} = 1 V$

(1) $T_{amb} = 175 \, ^{\circ}C$

(2) $T_{amb} = 150 \, ^{\circ}C$

(3) $T_{amb} = 125 \, ^{\circ}C$

(4) $T_{amb} = 100 \, ^{\circ}C$

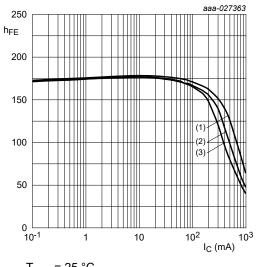
(5) $T_{amb} = 85 \, ^{\circ}C$

(6) T_{amb} = 25 °C

 $(7) T_{amb} = -40 °C$

(8) $T_{amb} = -55$ °C

BC817K-16H: DC current gain as a function of Fig. 7. collector current; typical values



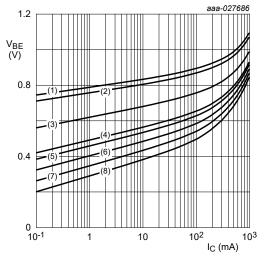
T_{amb} = 25 °C

(1) $V_{CE} = 5 V$

(2) $V_{CE} = 2 V$

(3) $V_{CE} = 1 V$

BC817K-16H: DC current gain as a function of Fig. 8. collector current; typical values



 $V_{CE} = 1 V$

(1) $T_{amb} = -55$ °C

(2) $T_{amb} = -40 \, ^{\circ}C$

(3) T_{amb} = 25 °C

(4) T_{amb} = 85 °C

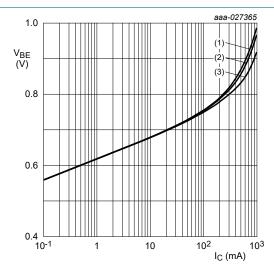
(5) $T_{amb} = 100 \, ^{\circ}C$

(6) $T_{amb} = 125 \, ^{\circ}C$

 $(7) T_{amb} = 150 °C$

(8) $T_{amb} = 175 \, ^{\circ}C$

BC817K-16H: Base-emitter voltage as a function Fig. 9. of collector current; typical values



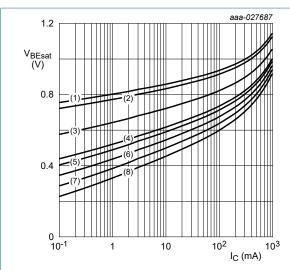
T_{amb} = 25 °C

(1) $V_{CE} = 1 V$

(2) $V_{CE} = 2 V$

(3) $V_{CE} = 5 V$

Fig. 10. BC817K-16H: Base-emitter voltage as a function of collector current; typical values



IC/IB = 10

(1) $T_{amb} = -55 \, ^{\circ}C$

(2) $T_{amb} = -40 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) T_{amb} = 85 °C

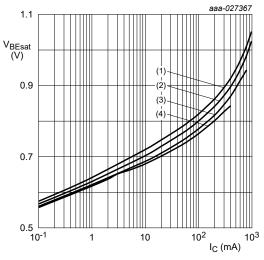
(5) $T_{amb} = 100 \, ^{\circ}C$

(6) $T_{amb} = 125 \, ^{\circ}C$

(7) T_{amb} = 150 °C

(8) $T_{amb} = 175 \, ^{\circ}C$





 $T_{amb} = 25 \, ^{\circ}C$

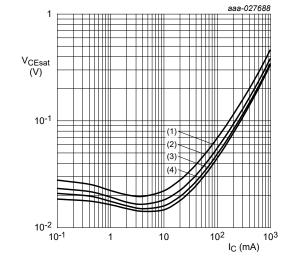
(1) IC/IB = 10

(2) IC/IB = 20

(3) IC/IB = 50

(4) IC/IB = 100

Fig. 12. BC817K-16H: Base-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$

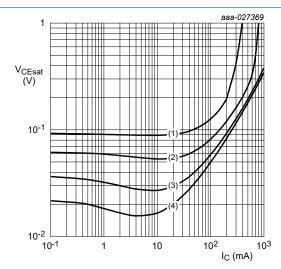
(1) $T_{amb} = 175 \, ^{\circ}C$

(2) $T_{amb} = 85 \, ^{\circ}C$

(3) T_{amb} = 25 °C

(4) $T_{amb} = -40 \, ^{\circ}C$

Fig. 13. BC817K-16H: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

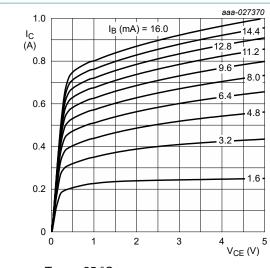
(1) IC/IB = 100

(2) IC/IB = 50

(3) IC/IB = 20

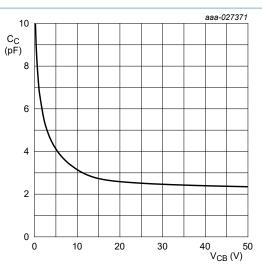
(4) IC/IB = 10

Fig. 14. BC817K-16H: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

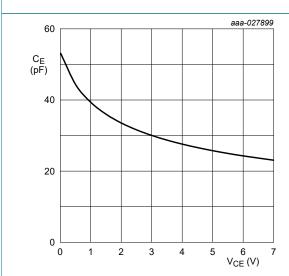
Fig. 15. BC817K-16H: Collector current as a function of collector-emitter voltage; typical values



f = 1 MHz

T_{amb} = 25 °C

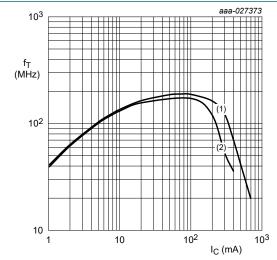
Fig. 16. BC817K-16H: Collector capacitance as a function of collector-base voltage; typical values



f = 1 MHz

T_{amb} = 25 °C

Fig. 17. BC817K-16H: Emitter capacitance as a function of emitter-base voltage; typical values



f = 100 MHz

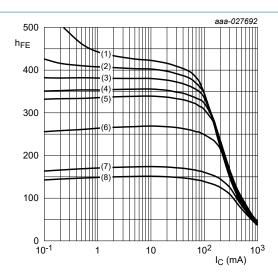
T_{amb} = 25 °C

(1) $V_{CE} = 5 V$

(2) $V_{CE} = 1 V$

Fig. 18. BC817K-16H: Transition frequency as a function of collector current; typical values

Rev. 2 — 30 September 2025



 $V_{CE} = 1 V$

(1) $T_{amb} = 175 \, ^{\circ}C$

(2) T_{amb} = 150 °C

(3) T_{amb} = 125 °C

(4) $T_{amb} = 100 \, ^{\circ}C$

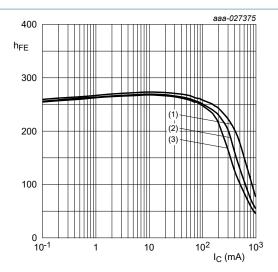
(5) T_{amb} = 85 °C

(6) T_{amb} = 25 °C

(7) $T_{amb} = -40 \, ^{\circ}C$

(8) $T_{amb} = -55 \, ^{\circ}C$





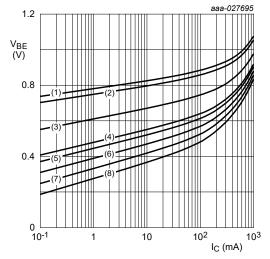
T_{amb} = 25 °C

(1) $V_{CE} = 5 V$

(2) $V_{CE} = 2 V$

(3) $V_{CE} = 1 V$

Fig. 20. BC817K-25H: DC current gain as a function of collector current; typical values



 $V_{CE} = 1 V$

(1) $T_{amb} = -55$ °C

(2) $T_{amb} = -40 \, ^{\circ}C$

(3) T_{amb} = 25 °C

(4) T_{amb} = 85 °C

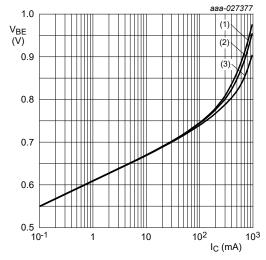
(5) $T_{amb} = 100 \, ^{\circ}C$

 $(6) T_{amb} = 100 C$ $(6) T_{amb} = 125 °C$

 $(7) T_{amb} = 123 °C$ $(7) T_{amb} = 150 °C$

(8) T_{amb} = 175 °C

Fig. 21. BC817K-25H: Base-emitter voltage as a function of collector current; typical values



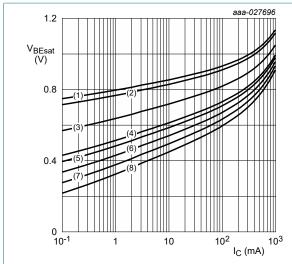
 $T_{amb} = 25 \, ^{\circ}C$

(1) $V_{CE} = 1 V$

(2) $V_{CE} = 2 V$

(3) $V_{CE} = 5 V$

Fig. 22. BC817K-25H: Base-emitter voltage as a function of collector current; typical values



IC/IB = 10

(1) $T_{amb} = -55 \, ^{\circ}C$

(2) $T_{amb} = -40 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) T_{amb} = 85 °C

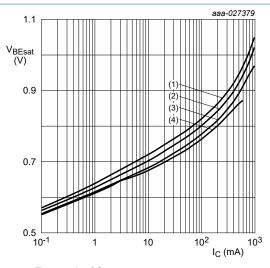
(5) $T_{amb} = 100 \, ^{\circ}C$

(6) $T_{amb} = 125 \, ^{\circ}C$

(7) T_{amb} = 150 °C

(8) T_{amb} = 175 °C





 $T_{amb} = 25 \, ^{\circ}C$

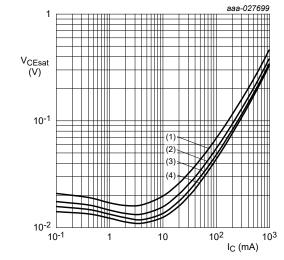
(1) IC/IB = 10

(2) IC/IB = 20

(3) IC/IB = 50

(4) IC/IB = 100

Fig. 24. BC817K-25H: Base-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$

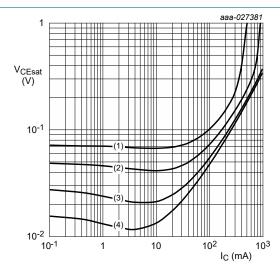
(1) $T_{amb} = 175 \, ^{\circ}C$

(2) $T_{amb} = 85 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) $T_{amb} = -40 \, ^{\circ}C$

Fig. 25. BC817K-25H: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

(1) IC/IB = 100

(2) IC/IB = 50

(3) IC/IB = 20

(4) IC/IB = 10

Fig. 26. BC817K-25H: Collector-emitter saturation voltage as a function of collector current; typical values

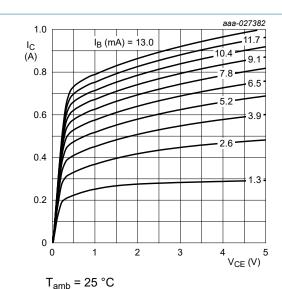
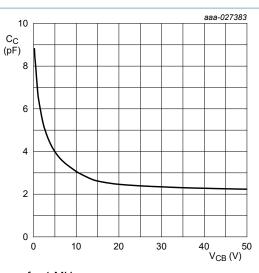
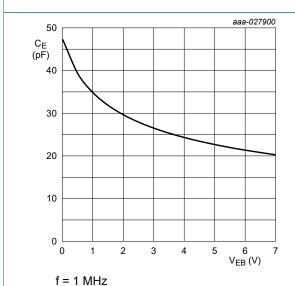


Fig. 27. BC817K-25H: Collector current as a function of collector-emitter voltage; typical values



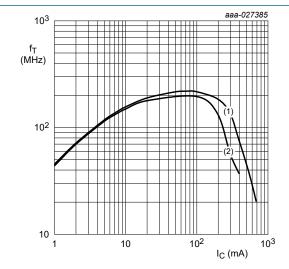
f = 1 MHz $T_{amb} = 25 °C$

Fig. 28. BC817K-25H: Collector capacitance as a function of collector-base voltage; typical values



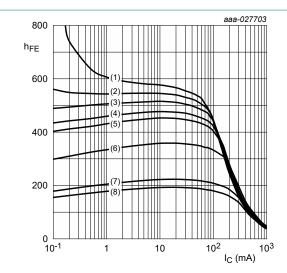
T_{amb} = 25 °C

Fig. 29. BC817K-25H: Emitter capacitance as a function of emitter-base voltage; typical values



f = 100 MHz $T_{amb} = 25 ^{\circ}\text{C}$ $(1) V_{CE} = 5 V$ $(2) V_{CE} = 1 V$

Fig. 30. BC817K-25H: Transition frequency as a function of collector current; typical values



 $V_{CE} = 1 V$

(1) $T_{amb} = 175 \, ^{\circ}C$

(2) T_{amb} = 150 °C

(3) $T_{amb} = 125 \, ^{\circ}C$

(4) T_{amb} = 100 °C

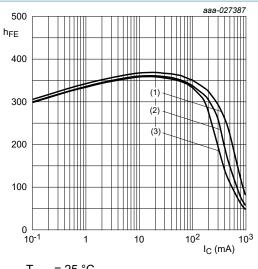
 $(5) T_{amb} = 85 °C$

(6) T_{amb} = 25 °C

 $(7) T_{amb} = -40 °C$

(8) $T_{amb} = -55 \, ^{\circ}C$





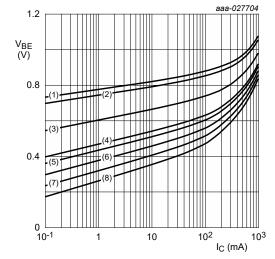
T_{amb} = 25 °C

(1) $V_{CE} = 5 V$

(2) $V_{CE} = 2 V$

(3) $V_{CE} = 1 V$

Fig. 32. BC817K-40H: DC current gain as a function of collector current; typical values



 $V_{CE} = 1 V$

(1) $T_{amb} = -55$ °C

(2) $T_{amb} = -40 \, ^{\circ}C$

(3) T_{amb} = 25 °C

(4) T_{amb} = 85 °C

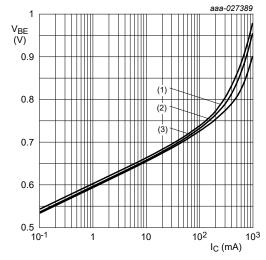
(5) $T_{amb} = 100 \, ^{\circ}C$

(6) T_{amb} = 125 °C

 $(7) T_{amb} = 150 °C$

(8) $T_{amb} = 175 \, ^{\circ}C$

Fig. 33. BC817K-40H: Base-emitter voltage as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

(1) $V_{CE} = 1 V$

(2) $V_{CE} = 2 V$

(3) $V_{CE} = 5 V$

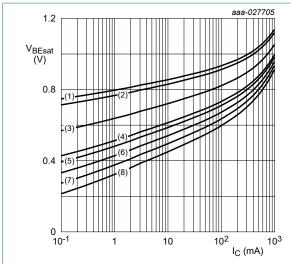
Fig. 34. BC817K-40H: Base-emitter voltage as a function of collector current; typical values

(2) (3)

V_{BEsat} (V)

0.9

0.7



IC/IB = 10

(1) $T_{amb} = -55 \, ^{\circ}C$

(2) $T_{amb} = -40 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) T_{amb} = 85 °C

(5) $T_{amb} = 100 \, ^{\circ}C$

(6) $T_{amb} = 125 \, ^{\circ}C$

(7) T_{amb} = 150 °C

(8) $T_{amb} = 175 \, ^{\circ}C$

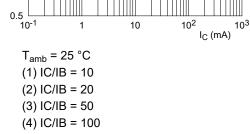
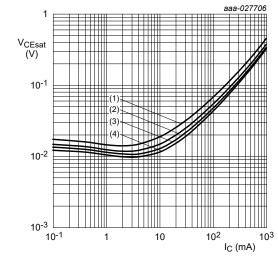


Fig. 36. BC817K-40H: Base-emitter saturation voltage as a function of collector current; typical values





 $I_{\rm C}/I_{\rm B} = 10$

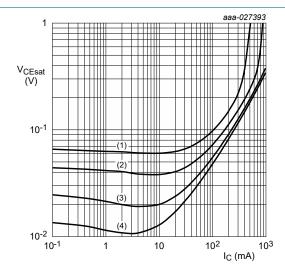
(1) $T_{amb} = 175 \, ^{\circ}C$

(2) $T_{amb} = 85 \, ^{\circ}C$

(3) $T_{amb} = 25 \, ^{\circ}C$

(4) $T_{amb} = -40 \, ^{\circ}C$

Fig. 37. BC817K-40H: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

(1) IC/IB = 100

(2) IC/IB = 50

(3) IC/IB = 20

(4) IC/IB = 10

Fig. 38. BC817K-40H: Collector-emitter saturation voltage as a function of collector current; typical values

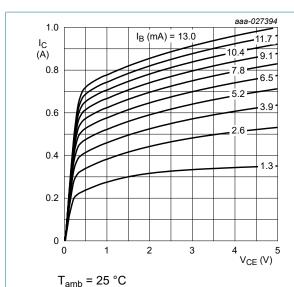
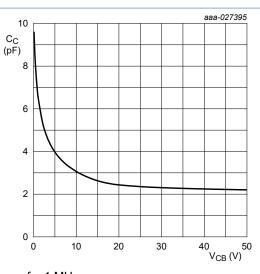
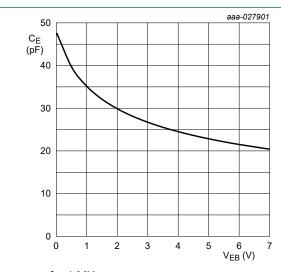


Fig. 39. BC817K-40H: Collector current as a function of collector-emitter voltage; typical values



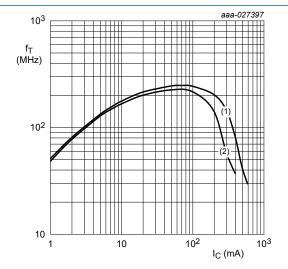
f = 1 MHz $T_{amb} = 25 °C$

Fig. 40. BC817K-40H: Collector capacitance as a function of collector-base voltage; typical values



f = 1 MHz $T_{amb} = 25 °C$

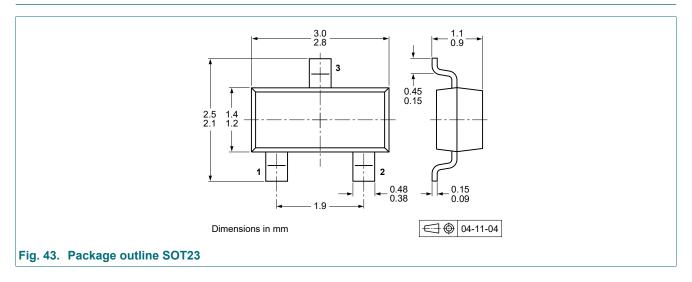
Fig. 41. BC817K-40H: Emitter capacitance as a function of emitter-base voltage; typical values



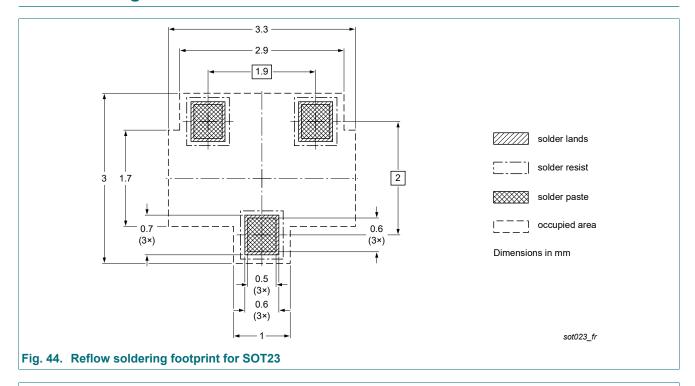
f = 100 MHz $T_{amb} = 25 ^{\circ}\text{C}$ $(1) V_{CE} = 5 V$ $(2) V_{CE} = 1 V$

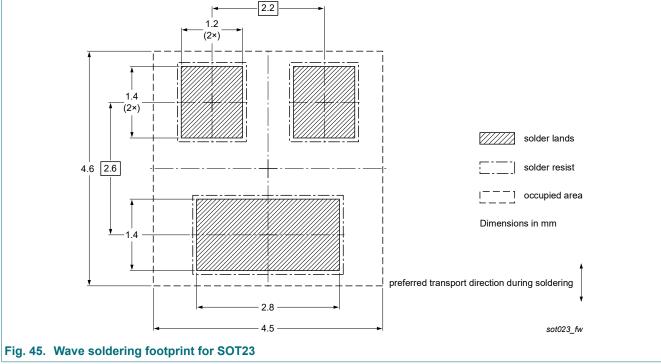
Fig. 42. BC817K-40H: Transition frequency as a function of collector current; typical values

11. Package outline



12. Soldering





13. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes					
BC817KH_SER v.2	20250930	Product data sheet	-	BC817KH_SER v.1					
Modifications:	\ /	Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).							
BC817KH_SER v.1	20190305	Product data sheet	-	-					

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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BC817KH_SER

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Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	5
10.	. Characteristics	7
11.	Package outline	. 17
12.	Soldering	. 18
13.	Revision history	.19
14.	Legal information	20

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21 / 21

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